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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Active
Number of LABs/CLBs	162000
Number of Logic Elements/Cells	2835000
Total RAM Bits	396150400
Number of I/O	572
Number of Gates	-
Voltage - Supply	0.825V ~ 0.876V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	2104-BBGA, FCBGA
Supplier Device Package	2104-FCBGA (47.5x47.5)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xcvu11p-2fsgd2104i

Table 3: **DC Characteristics Over Recommended Operating Conditions *(Cont'd)***

Symbol	Description	Min	Typ(1)	Max	Units
Uncalibrated programmable on-die termination in I/O banks (measured per JEDEC specification)					
$R^{(9)}$	Thevenin equivalent resistance of programmable input termination to $V_{CCO}/2$ where ODT = RTT_40.	–50%	40	+50%	Ω
	Thevenin equivalent resistance of programmable input termination to $V_{CCO}/2$ where ODT = RTT_48.	–50%	48	+50%	Ω
	Thevenin equivalent resistance of programmable input termination to $V_{CCO}/2$ where ODT = RTT_60.	–50%	60	+50%	Ω
	Programmable input termination to V_{CCO} where ODT = RTT_40.	–50%	40	+50%	Ω
	Programmable input termination to V_{CCO} where ODT = RTT_48.	–50%	48	+50%	Ω
	Programmable input termination to V_{CCO} where ODT = RTT_60.	–50%	60	+50%	Ω
	Programmable input termination to V_{CCO} where ODT = RTT_120.	–50%	120	+50%	Ω
	Programmable input termination to V_{CCO} where ODT = RTT_240.	–50%	240	+50%	Ω
Internal V_{REF}	50% V_{CCO}	V_{CCO} x 0.49	V_{CCO} x 0.50	V_{CCO} x 0.51	V
	70% V_{CCO}	V_{CCO} x 0.69	V_{CCO} x 0.70	V_{CCO} x 0.71	V
Differential termination	Programmable differential termination (TERM_100) for the I/O banks.	–35%	100	+35%	Ω
n	Temperature diode ideality factor.	–	1.026	–	–
r	Temperature diode series resistance.	–	2	–	Ω

Notes:

1. Typical values are specified at nominal voltage, 25°C.
2. For the I/O banks with a V_{CCO} of 1.8V and separated V_{CCO} and V_{CCAUX_IO} power supplies, the I_L maximum current is 70 µA.
3. This measurement represents the die capacitance at the pad, not including the package.
4. Maximum value specified for worst case process at 25°C.
5. I_{BATT} is measured when the battery-backed RAM (BBRAM) is enabled.
6. Do not program eFUSE during device configuration (e.g., during configuration, during configuration readback, or when readback CRC is active).
7. If VRP resides at a different bank (DCI cascade), the range increases to ±15%.
8. VRP resistor tolerance is (240Ω ±1%)
9. On-die input termination resistance, for more information see the *UltraScale Architecture SelectIO Resources User Guide* (UG571).

V_{IN} Maximum Allowed AC Voltage Overshoot and Undershoot

Table 4: **V_{IN} Maximum Allowed AC Voltage Overshoot and Undershoot for HP I/O Banks(1)(2)**

AC Voltage Overshoot	% of UI at –40°C to 100°C	AC Voltage Undershoot	% of UI at –40°C to 100°C
V_{CCO} + 0.30	100%	–0.30	100%
V_{CCO} + 0.35	100%	–0.35	90%
V_{CCO} + 0.40	92%	–0.40	92%
V_{CCO} + 0.45	50%	–0.45	50%
V_{CCO} + 0.50	20%	–0.50	20%
V_{CCO} + 0.55	10%	–0.55	10%
V_{CCO} + 0.60	6%	–0.60	6%
V_{CCO} + 0.65	2%	–0.65	2%
V_{CCO} + 0.70	2%	–0.70	2%

Notes:
1. A total of 200 mA per bank should not be exceeded.
2. For UI smaller than 20 µs.

Quiescent Supply Current

Table 5: **Typical Quiescent Supply Current(1)(2)(3)**

Symbol	Description	Device	Speed Grade and V_{CCINT} Operating Voltages				Units
			0.90V	0.85V		0.72V	
			-3	-2	-1	-2	
I_{CCINTQ}	Quiescent V_{CCINT} supply current.	XCVU3P	2384	2276	2276	2017	mA
		XCVU5P	4769	4552	4552	4034	mA
		XCVU7P	4769	4552	4552	4034	mA
		XCVU9P	7153	6828	6828	6050	mA
		XCVU11P	7567	7202	7202	6332	mA
		XCVU13P	10090	9602	9602	8442	mA
I_{CCINT_IOQ}	Quiescent current for V_{CCINT_IO} supply.	XCVU3P	149	144	144	144	mA
		XCVU5P	298	287	287	287	mA
		XCVU7P	298	287	287	287	mA
		XCVU9P	447	431	431	431	mA
		XCVU11P	182	176	176	176	mA
		XCVU13P	243	234	234	234	mA
I_{CCOQ}	Quiescent V_{CCO} supply current.	All devices	1	1	1	1	mA
I_{CCAUXQ}	Quiescent V_{CCAUX} supply current.	XCVU3P	268	268	268	268	mA
		XCVU5P	535	535	535	535	mA
		XCVU7P	535	535	535	535	mA
		XCVU9P	1015	1015	1015	1015	mA
		XCVU11P	819	819	819	819	mA
		XCVU13P	1091	1091	1091	1091	mA

DC Input and Output Levels

Values for V_{IL} and V_{IH} are recommended input voltages. Values for I_{OL} and I_{OH} are guaranteed over the recommended operating conditions at the V_{OL} and V_{OH} test points. Only selected standards are tested. These are chosen to ensure that all standards meet their specifications. The selected standards are tested at a minimum V_{CCO} with the respective V_{OL} and V_{OH} voltage levels shown. Other standards are sample tested.

Table 8: **SelectIO DC Input and Output Levels for the I/O Banks(1)(2)(3)**

I/O Standard	V_{IL}		V_{IH}		V_{OL}	V_{OH}	I_{OL}	I_{OH}
	V, Min	V, Max	V, Min	V, Max	V, Max	V, Min	mA	mA
HSTL_I	–0.300	V_{REF} – 0.100	V_{REF} + 0.100	V_{CCO} + 0.300	0.400	V_{CCO} – 0.400	5.8	–5.8
HSTL_I_12	–0.300	V_{REF} – 0.080	V_{REF} + 0.080	V_{CCO} + 0.300	25% V_{CCO}	75% V_{CCO}	4.1	–4.1
HSTL_I_18	–0.300	V_{REF} – 0.100	V_{REF} + 0.100	V_{CCO} + 0.300	0.400	V_{CCO} – 0.400	6.2	–6.2
HSUL_12	–0.300	V_{REF} – 0.130	V_{REF} + 0.130	V_{CCO} + 0.300	20% V_{CCO}	80% V_{CCO}	0.1	–0.1
LVCMOS12	–0.300	35% V_{CCO}	65% V_{CCO}	V_{CCO} + 0.300	0.400	V_{CCO} – 0.400	Note 4	Note 4
LVCMOS15	–0.300	35% V_{CCO}	65% V_{CCO}	V_{CCO} + 0.300	0.450	V_{CCO} – 0.450	Note 5	Note 5
LVCMOS18	–0.300	35% V_{CCO}	65% V_{CCO}	V_{CCO} + 0.300	0.450	V_{CCO} – 0.450	Note 5	Note 5
LVDCI_15	–0.300	35% V_{CCO}	65% V_{CCO}	V_{CCO} + 0.300	0.450	V_{CCO} – 0.450	7.0	–7.0
LVDCI_18	–0.300	35% V_{CCO}	65% V_{CCO}	V_{CCO} + 0.300	0.450	V_{CCO} – 0.450	7.0	–7.0
SSTL12	–0.300	V_{REF} – 0.100	V_{REF} + 0.100	V_{CCO} + 0.300	V_{CCO}/2 – 0.150	V_{CCO}/2 + 0.150	8.0	–8.0
SSTL135	–0.300	V_{REF} – 0.090	V_{REF} + 0.090	V_{CCO} + 0.300	V_{CCO}/2 – 0.150	V_{CCO}/2 + 0.150	9.0	–9.0
SSTL15	–0.300	V_{REF} – 0.100	V_{REF} + 0.100	V_{CCO} + 0.300	V_{CCO}/2 – 0.175	V_{CCO}/2 + 0.175	10.0	–10.0
SSTL18_I	–0.300	V_{REF} – 0.125	V_{REF} + 0.125	V_{CCO} + 0.300	V_{CCO}/2 – 0.470	V_{CCO}/2 + 0.470	7.0	–7.0
MIPI_DPHY_DCI_LP(6)	–0.300	0.550	0.880	V_{CCO} + 0.300	0.050	1.100	0.01	–0.01

Notes:

1. Tested according to relevant specifications.
2. Standards specified using the default I/O standard configuration. For details, see the *UltraScale Architecture SelectIO Resources User Guide* (UG571).
3. POD10 and POD12 DC input and output levels are shown in Table 9, Table 13, and Table 14.
4. Supported drive strengths of 2, 4, 6, or 8 mA in the I/O banks.
5. Supported drive strengths of 2, 4, 6, 8, or 12 mA in the I/O banks.
6. Low-power option for MIPI_DPHY_DCI.

Table 9: **DC Input Levels for Single-ended POD10 and POD12 I/O Standards(1)(2)**

I/O Standard	V_{IL}		V_{IH}	
	V, Min	V, Max	V, Min	V, Max
POD10	–0.300	V_{REF} – 0.068	V_{REF} + 0.068	V_{CCO} + 0.300
POD12	–0.300	V_{REF} – 0.068	V_{REF} + 0.068	V_{CCO} + 0.300

Notes:

1. Tested according to relevant specifications.
2. Standards specified using the default I/O standard configuration. For details, see the *UltraScale Architecture SelectIO Resources User Guide* (UG571).

Table 13: **DC Output Levels for Single-ended and Differential POD10 and POD12 Standards(1)(2)**

Symbol	Description	V_{OUT}	Min	Typ	Max	Units
R_{OL}	Pull-down resistance.	V_{OM_DC} (as described in Table 14)	36	40	44	Ω
R_{OH}	Pull-up resistance.	V_{OM_DC} (as described in Table 14)	36	40	44	Ω

Notes:

1. Tested according to relevant specifications.
2. Standards specified using the default I/O standard configuration. For details, see the *UltraScale Architecture SelectIO Resources User Guide* (UG571).

Table 14: **Table 13 Definitions for DC Output Levels for POD Standards**

Symbol	Description	All Speed Grades	Units
V_{OM_DC}	DC output Mid measurement level (for IV curve linearity).	0.8 x V_{CCO}	V

LVDS DC Specifications (LVDS)

Table 15: **LVDS DC Specifications**

Symbol	DC Parameter	Conditions	Min	Typ	Max	Units
V_{CCO}(1)	Supply voltage.		1.710	1.800	1.890	V
V_{ODIFF}(2)	Differential output voltage: ($\underline{Q}$ – $\overline{Q}$), $\underline{Q}$ = High ($\underline{Q}$ – $\overline{Q}$), $\overline{Q}$ = High	R_T = 100Ω across Q and $\overline{Q}$ signals	247	350	454	mV
V_{OCM}(2)	Output common-mode voltage.	R_T = 100 Ω across Q and $\overline{Q}$ signals	1.000	1.250	1.425	V
V_{IDIFF}	Differential input voltage: ($\underline{Q}$ – $\overline{Q}$), $\underline{Q}$ = High ($\underline{Q}$ – $\overline{Q}$), $\overline{Q}$ = High		100	350	600(3)	mV
V_{ICM_DC}(4)	Input common-mode voltage (DC coupling).		0.300	1.200	1.425	V
V_{ICM_AC}(5)	Input common-mode voltage (AC coupling).		0.600	–	1.100	V

Notes:

1. In I/O banks, when LVDS is used with input-only functionality, it can be placed in a bank where the V_{CCO} levels are different from the specified level only if internal differential termination is not used. In this scenario, V_{CCO} must be chosen to ensure the input pin voltage levels do not violate the *Recommended Operating Condition* (Table 2) specification for the V_{IN} I/O pin voltage.
2. V_{OCM} and V_{ODIFF} values are for LVDS_PRE_EMPHASIS = FALSE.
3. Maximum V_{IDIFF} value is specified for the maximum V_{ICM} specification. With a lower V_{ICM}, a higher V_{DIFF} is tolerated only when the recommended operating conditions and overshoot/undershoot V_{IN} specifications are maintained.
4. Input common mode voltage for DC coupled configurations. EQUALIZATION = EQ_NONE (Default).
5. External input common mode voltage specification for AC coupled configurations. EQUALIZATION = EQ_LEVEL0, EQ_LEVEL1, EQ_LEVEL2, EQ_LEVEL3, EQ_LEVEL4.

Production Silicon and Software Status

In some cases, a particular family member (and speed grade) is released to production before a speed specification is released with the correct label (Advance, Preliminary, Production). Any labeling discrepancies are corrected in subsequent speed specification releases.

Table 18 lists the production released Virtex UltraScale+ FPGA, speed grade, and the minimum corresponding supported speed specification version and Vivado software revisions. The Vivado software and speed specifications listed are the minimum releases required for production. All subsequent releases of software and speed specifications are valid.

Table 18: **Virtex UltraScale+ FPGA Device Production Software and Speed Specification Release**

Device	Speed Grade and V_{CCINT} Operating Voltages				
	0.90V	0.85V			0.72V
	-3	-2	-1	-2L	-2L
XCVU3P		Vivado tools 2017.1 v1.10			
XCVU5P					
XCVU7P					
XCVU9P					
XCVU11P					
XCVU13P					

Notes:

1. Blank entries indicate a device and/or speed grade in Advance or Preliminary status.

FPGA Logic Switching Characteristics

Table 24, high-performance IOB (HP), summarizes the values of standard-specific data input delay adjustments, output delays terminating at pads (based on standard) and 3-state delays.

- $T_{INBUF\_DELAY\_PAD\_I}$ is the delay from IOB pad through the input buffer to the I-pin of an IOB pad. The delay varies depending on the capability of the SelectIO input buffer.
- $T_{OUTBUF\_DELAY\_O\_PAD}$ is the delay from the O pin to the IOB pad through the output buffer of an IOB pad. The delay varies depending on the capability of the SelectIO output buffer.
- $T_{OUTBUF\_DELAY\_TD\_PAD}$ is the delay from the T pin to the IOB pad through the output buffer of an IOB pad, when 3-state is disabled. The delay varies depending on the SelectIO capability of the output buffer. In HP I/O banks, the internal DCI termination turn-on time is always faster than $T_{OUTBUF\_DELAY\_TD\_PAD}$ when the DCITERMDISABLE pin is used.

IOB High Performance (HP) Switching Characteristics

Table 24: **IOB High Performance (HP) Switching Characteristics**

I/O Standards	$T_{INBUF\_DELAY\_PAD\_I}$				$T_{OUTBUF\_DELAY\_O\_PAD}$				$T_{OUTBUF\_DELAY\_TD\_PAD}$				Units
	0.90V	0.85V		0.72V	0.90V	0.85V		0.72V	0.90V	0.85V		0.72V	
	-3	-2	-1	-2	-3	-2	-1	-2	-3	-2	-1	-2	
DIFF_HSTL_I_12_F	0.394	0.394	0.402	0.394	0.423	0.423	0.443	0.423	0.553	0.553	0.582	0.553	ns
DIFF_HSTL_I_12_M	0.394	0.394	0.402	0.394	0.552	0.552	0.583	0.552	0.641	0.641	0.679	0.641	ns
DIFF_HSTL_I_12_S	0.394	0.394	0.402	0.394	0.752	0.752	0.800	0.752	0.813	0.813	0.868	0.813	ns
DIFF_HSTL_I_18_F	0.319	0.319	0.339	0.319	0.456	0.456	0.474	0.456	0.576	0.576	0.606	0.576	ns
DIFF_HSTL_I_18_M	0.319	0.319	0.339	0.319	0.570	0.570	0.603	0.570	0.653	0.653	0.692	0.653	ns
DIFF_HSTL_I_18_S	0.319	0.319	0.339	0.319	0.782	0.782	0.834	0.782	0.816	0.816	0.871	0.816	ns
DIFF_HSTL_I_DCI_12_F	0.394	0.394	0.402	0.394	0.406	0.406	0.429	0.406	0.534	0.534	0.564	0.534	ns
DIFF_HSTL_I_DCI_12_M	0.394	0.394	0.402	0.394	0.557	0.557	0.587	0.557	0.653	0.653	0.694	0.653	ns
DIFF_HSTL_I_DCI_12_S	0.394	0.394	0.402	0.394	0.755	0.755	0.806	0.755	0.842	0.842	0.907	0.842	ns
DIFF_HSTL_I_DCI_18_F	0.323	0.323	0.339	0.323	0.445	0.445	0.461	0.445	0.566	0.566	0.595	0.566	ns
DIFF_HSTL_I_DCI_18_M	0.323	0.323	0.339	0.323	0.555	0.555	0.586	0.555	0.643	0.643	0.684	0.643	ns
DIFF_HSTL_I_DCI_18_S	0.323	0.323	0.339	0.323	0.762	0.762	0.818	0.762	0.836	0.836	0.900	0.836	ns
DIFF_HSTL_I_DCI_F	0.397	0.397	0.417	0.397	0.431	0.431	0.445	0.431	0.555	0.555	0.575	0.555	ns
DIFF_HSTL_I_DCI_M	0.397	0.397	0.417	0.397	0.553	0.553	0.583	0.553	0.644	0.644	0.684	0.644	ns
DIFF_HSTL_I_DCI_S	0.397	0.397	0.417	0.397	0.767	0.767	0.823	0.767	0.848	0.848	0.912	0.848	ns
DIFF_HSTL_I_F	0.404	0.404	0.417	0.404	0.423	0.423	0.443	0.423	0.549	0.549	0.581	0.549	ns
DIFF_HSTL_I_M	0.404	0.404	0.417	0.404	0.555	0.555	0.586	0.555	0.640	0.640	0.677	0.640	ns
DIFF_HSTL_I_S	0.404	0.404	0.417	0.404	0.767	0.767	0.818	0.767	0.811	0.811	0.866	0.811	ns
DIFF_HSUL_12_DCI_F	0.381	0.381	0.400	0.381	0.425	0.425	0.443	0.425	0.558	0.558	0.586	0.558	ns
DIFF_HSUL_12_DCI_M	0.381	0.381	0.400	0.381	0.557	0.557	0.587	0.557	0.653	0.653	0.694	0.653	ns
DIFF_HSUL_12_DCI_S	0.381	0.381	0.400	0.381	0.737	0.737	0.787	0.737	0.822	0.822	0.885	0.822	ns
DIFF_HSUL_12_F	0.394	0.394	0.402	0.394	0.412	0.412	0.430	0.412	0.538	0.538	0.566	0.538	ns
DIFF_HSUL_12_M	0.394	0.394	0.402	0.394	0.552	0.552	0.583	0.552	0.641	0.641	0.679	0.641	ns
DIFF_HSUL_12_S	0.394	0.394	0.402	0.394	0.752	0.752	0.800	0.752	0.813	0.813	0.868	0.813	ns

Table 24: **IOB High Performance (HP) Switching Characteristics *(Cont'd)***

I/O Standards	$T_{INBUF\_DELAY\_PAD\_I}$				$T_{OUTBUF\_DELAY\_O\_PAD}$				$T_{OUTBUF\_DELAY\_TD\_PAD}$				Units
	0.90V	0.85V		0.72V	0.90V	0.85V		0.72V	0.90V	0.85V		0.72V	
	-3	-2	-1	-2	-3	-2	-1	-2	-3	-2	-1	-2	
HSLVDCI_18_S	0.424	0.424	0.447	0.424	0.761	0.761	0.817	0.761	0.836	0.836	0.900	0.836	ns
HSTL_I_12_F	0.378	0.378	0.399	0.378	0.423	0.423	0.443	0.423	0.553	0.553	0.582	0.553	ns
HSTL_I_12_M	0.378	0.378	0.399	0.378	0.551	0.551	0.582	0.551	0.642	0.642	0.679	0.642	ns
HSTL_I_12_S	0.378	0.378	0.399	0.378	0.750	0.750	0.799	0.750	0.813	0.813	0.868	0.813	ns
HSTL_I_18_F	0.322	0.322	0.339	0.322	0.456	0.456	0.474	0.456	0.576	0.576	0.606	0.576	ns
HSTL_I_18_M	0.322	0.322	0.339	0.322	0.569	0.569	0.602	0.569	0.653	0.653	0.692	0.653	ns
HSTL_I_18_S	0.322	0.322	0.339	0.322	0.781	0.781	0.833	0.781	0.816	0.816	0.871	0.816	ns
HSTL_I_DCI_12_F	0.378	0.378	0.399	0.378	0.406	0.406	0.429	0.406	0.534	0.534	0.564	0.534	ns
HSTL_I_DCI_12_M	0.378	0.378	0.399	0.378	0.556	0.556	0.586	0.556	0.654	0.654	0.694	0.654	ns
HSTL_I_DCI_12_S	0.378	0.378	0.399	0.378	0.754	0.754	0.803	0.754	0.842	0.842	0.907	0.842	ns
HSTL_I_DCI_18_F	0.321	0.321	0.339	0.321	0.445	0.445	0.461	0.445	0.566	0.566	0.595	0.566	ns
HSTL_I_DCI_18_M	0.321	0.321	0.339	0.321	0.554	0.554	0.585	0.554	0.643	0.643	0.684	0.643	ns
HSTL_I_DCI_18_S	0.321	0.321	0.339	0.321	0.761	0.761	0.817	0.761	0.836	0.836	0.900	0.836	ns
HSTL_I_DCI_F	0.393	0.393	0.415	0.393	0.431	0.431	0.445	0.431	0.555	0.555	0.575	0.555	ns
HSTL_I_DCI_M	0.393	0.393	0.415	0.393	0.552	0.552	0.581	0.552	0.644	0.644	0.684	0.644	ns
HSTL_I_DCI_S	0.393	0.393	0.415	0.393	0.766	0.766	0.821	0.766	0.847	0.847	0.912	0.847	ns
HSTL_I_F	0.378	0.378	0.399	0.378	0.423	0.423	0.443	0.423	0.549	0.549	0.581	0.549	ns
HSTL_I_M	0.378	0.378	0.399	0.378	0.554	0.554	0.585	0.554	0.640	0.640	0.677	0.640	ns
HSTL_I_S	0.378	0.378	0.399	0.378	0.766	0.766	0.816	0.766	0.811	0.811	0.866	0.811	ns
HSUL_12_DCI_F	0.378	0.378	0.399	0.378	0.425	0.425	0.443	0.425	0.558	0.558	0.586	0.558	ns
HSUL_12_DCI_M	0.378	0.378	0.399	0.378	0.556	0.556	0.586	0.556	0.654	0.654	0.694	0.654	ns
HSUL_12_DCI_S	0.378	0.378	0.399	0.378	0.736	0.736	0.784	0.736	0.821	0.821	0.886	0.821	ns
HSUL_12_F	0.378	0.378	0.399	0.378	0.412	0.412	0.430	0.412	0.538	0.538	0.566	0.538	ns
HSUL_12_M	0.378	0.378	0.399	0.378	0.551	0.551	0.582	0.551	0.642	0.642	0.679	0.642	ns
HSUL_12_S	0.378	0.378	0.399	0.378	0.750	0.750	0.799	0.750	0.813	0.813	0.868	0.813	ns
LVCMOS12_F_2	0.512	0.512	0.555	0.512	0.672	0.672	0.692	0.672	0.898	0.898	0.922	0.898	ns
LVCMOS12_F_4	0.512	0.512	0.555	0.512	0.504	0.504	0.521	0.504	0.664	0.664	0.693	0.664	ns
LVCMOS12_F_6	0.512	0.512	0.555	0.512	0.485	0.485	0.507	0.485	0.634	0.634	0.669	0.634	ns
LVCMOS12_F_8	0.512	0.512	0.555	0.512	0.465	0.465	0.489	0.465	0.611	0.611	0.666	0.611	ns
LVCMOS12_M_2	0.512	0.512	0.555	0.512	0.708	0.708	0.727	0.708	0.916	0.916	0.945	0.916	ns
LVCMOS12_M_4	0.512	0.512	0.555	0.512	0.550	0.550	0.573	0.550	0.664	0.664	0.690	0.664	ns
LVCMOS12_M_6	0.512	0.512	0.555	0.512	0.527	0.527	0.554	0.527	0.622	0.622	0.652	0.622	ns
LVCMOS12_M_8	0.512	0.512	0.555	0.512	0.540	0.540	0.571	0.540	0.614	0.614	0.649	0.614	ns
LVCMOS12_S_2	0.512	0.512	0.555	0.512	0.767	0.767	0.803	0.767	0.990	0.990	1.024	0.990	ns
LVCMOS12_S_4	0.512	0.512	0.555	0.512	0.666	0.666	0.704	0.666	0.803	0.803	0.848	0.803	ns
LVCMOS12_S_6	0.512	0.512	0.555	0.512	0.657	0.657	0.695	0.657	0.732	0.732	0.774	0.732	ns
LVCMOS12_S_8	0.512	0.512	0.555	0.512	0.708	0.708	0.761	0.708	0.745	0.745	0.790	0.745	ns
LVCMOS15_F_12	0.414	0.414	0.445	0.414	0.500	0.500	0.522	0.500	0.647	0.647	0.682	0.647	ns
LVCMOS15_F_2	0.414	0.414	0.445	0.414	0.702	0.702	0.722	0.702	0.919	0.919	0.940	0.919	ns
LVCMOS15_F_4	0.414	0.414	0.445	0.414	0.579	0.579	0.601	0.579	0.755	0.755	0.781	0.755	ns
LVCMOS15_F_6	0.414	0.414	0.445	0.414	0.547	0.547	0.569	0.547	0.711	0.711	0.742	0.711	ns

Table 24: **IOB High Performance (HP) Switching Characteristics *(Cont'd)***

I/O Standards	$T_{INBUF\_DELAY\_PAD\_I}$				$T_{OUTBUF\_DELAY\_O\_PAD}$				$T_{OUTBUF\_DELAY\_TD\_PAD}$				Units
	0.90V	0.85V		0.72V	0.90V	0.85V		0.72V	0.90V	0.85V		0.72V	
	-3	-2	-1	-2	-3	-2	-1	-2	-3	-2	-1	-2	
LVCMOS15_F_8	0.414	0.414	0.445	0.414	0.518	0.518	0.538	0.518	0.686	0.686	0.703	0.686	ns
LVCMOS15_M_12	0.414	0.414	0.445	0.414	0.607	0.607	0.644	0.607	0.637	0.637	0.676	0.637	ns
LVCMOS15_M_2	0.414	0.414	0.445	0.414	0.741	0.741	0.770	0.741	0.938	0.938	0.962	0.938	ns
LVCMOS15_M_4	0.414	0.414	0.445	0.414	0.625	0.625	0.651	0.625	0.754	0.754	0.786	0.754	ns
LVCMOS15_M_6	0.414	0.414	0.445	0.414	0.576	0.576	0.604	0.576	0.674	0.674	0.710	0.674	ns
LVCMOS15_M_8	0.414	0.414	0.445	0.414	0.568	0.568	0.601	0.568	0.639	0.639	0.681	0.639	ns
LVCMOS15_S_12	0.414	0.414	0.445	0.414	0.788	0.788	0.855	0.788	0.695	0.695	0.733	0.695	ns
LVCMOS15_S_2	0.414	0.414	0.445	0.414	0.829	0.829	0.864	0.829	1.039	1.039	1.079	1.039	ns
LVCMOS15_S_4	0.414	0.414	0.445	0.414	0.687	0.687	0.725	0.687	0.813	0.813	0.851	0.813	ns
LVCMOS15_S_6	0.414	0.414	0.445	0.414	0.671	0.671	0.710	0.671	0.726	0.726	0.763	0.726	ns
LVCMOS15_S_8	0.414	0.414	0.445	0.414	0.704	0.704	0.755	0.704	0.721	0.721	0.758	0.721	ns
LVCMOS18_F_12	0.418	0.418	0.445	0.418	0.573	0.573	0.601	0.573	0.731	0.731	0.769	0.731	ns
LVCMOS18_F_2	0.418	0.418	0.445	0.418	0.739	0.739	0.760	0.739	0.945	0.945	0.971	0.945	ns
LVCMOS18_F_4	0.418	0.418	0.445	0.418	0.609	0.609	0.630	0.609	0.778	0.778	0.802	0.778	ns
LVCMOS18_F_6	0.418	0.418	0.445	0.418	0.603	0.603	0.633	0.603	0.781	0.781	0.808	0.781	ns
LVCMOS18_F_8	0.418	0.418	0.445	0.418	0.573	0.573	0.600	0.573	0.733	0.733	0.767	0.733	ns
LVCMOS18_M_12	0.418	0.418	0.445	0.418	0.640	0.640	0.678	0.640	0.670	0.670	0.709	0.670	ns
LVCMOS18_M_2	0.418	0.418	0.445	0.418	0.798	0.798	0.822	0.798	0.991	0.991	1.016	0.991	ns
LVCMOS18_M_4	0.418	0.418	0.445	0.418	0.664	0.664	0.693	0.664	0.798	0.798	0.836	0.798	ns
LVCMOS18_M_6	0.418	0.418	0.445	0.418	0.629	0.629	0.663	0.629	0.735	0.735	0.775	0.735	ns
LVCMOS18_M_8	0.418	0.418	0.445	0.418	0.626	0.626	0.661	0.626	0.705	0.705	0.746	0.705	ns
LVCMOS18_S_12	0.418	0.418	0.445	0.418	0.795	0.795	0.861	0.795	0.683	0.683	0.721	0.683	ns
LVCMOS18_S_2	0.418	0.418	0.445	0.418	0.862	0.862	0.897	0.862	1.076	1.076	1.098	1.076	ns
LVCMOS18_S_4	0.418	0.418	0.445	0.418	0.716	0.716	0.758	0.716	0.829	0.829	0.872	0.829	ns
LVCMOS18_S_6	0.418	0.418	0.445	0.418	0.682	0.682	0.724	0.682	0.724	0.724	0.762	0.724	ns
LVCMOS18_S_8	0.418	0.418	0.445	0.418	0.707	0.707	0.760	0.707	0.709	0.709	0.745	0.709	ns
LVDCI_15_F	0.425	0.425	0.462	0.425	0.426	0.426	0.443	0.426	0.548	0.548	0.581	0.548	ns
LVDCI_15_M	0.425	0.425	0.462	0.425	0.553	0.553	0.582	0.553	0.645	0.645	0.685	0.645	ns
LVDCI_15_S	0.425	0.425	0.462	0.425	0.749	0.749	0.803	0.749	0.821	0.821	0.890	0.821	ns
LVDCI_18_F	0.414	0.414	0.447	0.414	0.441	0.441	0.459	0.441	0.560	0.560	0.589	0.560	ns
LVDCI_18_M	0.414	0.414	0.447	0.414	0.554	0.554	0.585	0.554	0.644	0.644	0.683	0.644	ns
LVDCI_18_S	0.414	0.414	0.447	0.414	0.760	0.760	0.818	0.760	0.837	0.837	0.899	0.837	ns
LVDS	0.539	0.539	0.620	0.539	0.626	0.626	0.662	0.626	960.447	960.447	960.447	960.447	ns
MIPI_DPHY_DCI_HS	0.386	0.386	0.415	0.386	0.502	0.502	0.522	0.502	N/A	N/A	N/A	N/A	ns
MIPI_DPHY_DCI_LP	8.438	8.438	8.792	8.438	0.914	0.914	0.937	0.914	N/A	N/A	N/A	N/A	ns
POD10_DCI_F	0.408	0.408	0.430	0.408	0.425	0.425	0.444	0.425	0.555	0.555	0.584	0.555	ns
POD10_DCI_M	0.408	0.408	0.430	0.408	0.542	0.542	0.571	0.542	0.640	0.640	0.681	0.640	ns
POD10_DCI_S	0.408	0.408	0.430	0.408	0.754	0.754	0.815	0.754	0.850	0.850	0.917	0.850	ns
POD10_F	0.407	0.407	0.430	0.407	0.438	0.438	0.459	0.438	0.569	0.569	0.601	0.569	ns
POD10_M	0.407	0.407	0.430	0.407	0.538	0.538	0.568	0.538	0.630	0.630	0.667	0.630	ns
POD10_S	0.407	0.407	0.430	0.407	0.766	0.766	0.821	0.766	0.836	0.836	0.894	0.836	ns

Table 24: **IOB High Performance (HP) Switching Characteristics *(Cont'd)***

I/O Standards	$T_{INBUF\_DELAY\_PAD\_I}$				$T_{OUTBUF\_DELAY\_O\_PAD}$				$T_{OUTBUF\_DELAY\_TD\_PAD}$				Units
	0.90V	0.85V		0.72V	0.90V	0.85V		0.72V	0.90V	0.85V		0.72V	
	-3	-2	-1	-2	-3	-2	-1	-2	-3	-2	-1	-2	
POD12_DCI_F	0.409	0.409	0.431	0.409	0.425	0.425	0.443	0.425	0.558	0.558	0.586	0.558	ns
POD12_DCI_M	0.409	0.409	0.431	0.409	0.543	0.543	0.572	0.543	0.638	0.638	0.678	0.638	ns
POD12_DCI_S	0.409	0.409	0.431	0.409	0.772	0.772	0.822	0.772	0.862	0.862	0.929	0.862	ns
POD12_F	0.409	0.409	0.431	0.409	0.455	0.455	0.476	0.455	0.595	0.595	0.626	0.595	ns
POD12_M	0.409	0.409	0.431	0.409	0.551	0.551	0.582	0.551	0.641	0.641	0.679	0.641	ns
POD12_S	0.409	0.409	0.431	0.409	0.767	0.767	0.817	0.767	0.832	0.832	0.889	0.832	ns
SLVS_400_18	0.539	0.539	0.620	0.539	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A	ns
SSTL12_DCI_F	0.381	0.381	0.399	0.381	0.425	0.425	0.443	0.425	0.558	0.558	0.586	0.558	ns
SSTL12_DCI_M	0.381	0.381	0.399	0.381	0.557	0.557	0.587	0.557	0.654	0.654	0.694	0.654	ns
SSTL12_DCI_S	0.381	0.381	0.399	0.381	0.754	0.754	0.803	0.754	0.842	0.842	0.908	0.842	ns
SSTL12_F	0.403	0.403	0.403	0.403	0.412	0.412	0.430	0.412	0.538	0.538	0.566	0.538	ns
SSTL12_M	0.403	0.403	0.403	0.403	0.553	0.553	0.584	0.553	0.641	0.641	0.676	0.641	ns
SSTL12_S	0.403	0.403	0.403	0.403	0.758	0.758	0.808	0.758	0.823	0.823	0.879	0.823	ns
SSTL135_DCI_F	0.366	0.366	0.399	0.366	0.411	0.411	0.428	0.411	0.537	0.537	0.565	0.537	ns
SSTL135_DCI_M	0.366	0.366	0.399	0.366	0.551	0.551	0.582	0.551	0.645	0.645	0.685	0.645	ns
SSTL135_DCI_S	0.366	0.366	0.399	0.366	0.746	0.746	0.799	0.746	0.829	0.829	0.893	0.829	ns
SSTL135_F	0.378	0.378	0.399	0.378	0.408	0.408	0.428	0.408	0.528	0.528	0.561	0.528	ns
SSTL135_M	0.378	0.378	0.399	0.378	0.555	0.555	0.585	0.555	0.641	0.641	0.679	0.641	ns
SSTL135_S	0.378	0.378	0.399	0.378	0.772	0.772	0.823	0.772	0.827	0.827	0.878	0.827	ns
SSTL15_DCI_F	0.402	0.402	0.417	0.402	0.412	0.412	0.429	0.412	0.531	0.531	0.563	0.531	ns
SSTL15_DCI_M	0.402	0.402	0.417	0.402	0.553	0.553	0.583	0.553	0.645	0.645	0.685	0.645	ns
SSTL15_DCI_S	0.402	0.402	0.417	0.402	0.768	0.768	0.822	0.768	0.847	0.847	0.912	0.847	ns
SSTL15_F	0.371	0.371	0.400	0.371	0.408	0.408	0.428	0.408	0.530	0.530	0.556	0.530	ns
SSTL15_M	0.371	0.371	0.400	0.371	0.554	0.554	0.585	0.554	0.639	0.639	0.677	0.639	ns
SSTL15_S	0.371	0.371	0.400	0.371	0.767	0.767	0.817	0.767	0.813	0.813	0.867	0.813	ns
SSTL18_I_DCI_F	0.329	0.329	0.336	0.329	0.445	0.445	0.461	0.445	0.566	0.566	0.595	0.566	ns
SSTL18_I_DCI_M	0.329	0.329	0.336	0.329	0.554	0.554	0.585	0.554	0.644	0.644	0.683	0.644	ns
SSTL18_I_DCI_S	0.329	0.329	0.336	0.329	0.762	0.762	0.818	0.762	0.837	0.837	0.899	0.837	ns
SSTL18_I_F	0.316	0.316	0.337	0.316	0.454	0.454	0.476	0.454	0.578	0.578	0.608	0.578	ns
SSTL18_I_M	0.316	0.316	0.337	0.316	0.571	0.571	0.603	0.571	0.652	0.652	0.692	0.652	ns
SSTL18_I_S	0.316	0.316	0.337	0.316	0.782	0.782	0.835	0.782	0.816	0.816	0.870	0.816	ns
SUB_LVDS	0.539	0.539	0.620	0.539	0.660	0.660	0.692	0.660	969.863	969.863	969.863	969.863	ns

IOB 3-state Output Switching Characteristics

Table 25 specifies the values of $T_{OUTBUF\_DELAY\_TE\_PAD}$ and $T_{INBUF\_DELAY\_IBUFDIS\_O}$. $T_{OUTBUF\_DELAY\_TE\_PAD}$ is the delay from the T pin to the IOB pad through the output buffer of an IOB pad, when 3-state is enabled (i.e., a high impedance state). $T_{INBUF\_DELAY\_IBUFDIS\_O}$ is the IOB delay from IBUFDISABLE to O output. In HP I/O banks, the internal DCI termination turn-off time is always faster than $T_{OUTBUF\_DELAY\_TE\_PAD}$ when the DCITERMDISABLE pin is used.

Table 25: **IOB 3-state Output Switching Characteristics**

Symbol	Description	Speed Grade and V_{CCINT} Operating Voltages				Units
		0.90V	0.85V		0.72V	
		-3	-2	-1	-2	
$T_{OUTBUF\_DELAY\_TE\_PAD}$	T input to pad high-impedance for the I/O banks	5.330	5.330	5.341	5.330	ns
$T_{INBUF\_DELAY\_IBUFDIS\_O}$	IBUF turn-on time from IBUFDISABLE to O output for the I/O banks	0.936	0.936	1.037	0.936	ns

Input Delay Measurement Methodology

Table 26 shows the test setup parameters used for measuring input delay.

Table 26: **Input Delay Measurement Methodology**

Description	I/O Standard Attribute	V_L (1)(2)	V_H (1)(2)	V_{MEAS} (1)(4)(6)	V_{REF} (1)(3)(5)
LVCMOS, 1.2V	LVCMOS12	0.1	1.1	0.6	–
LVCMOS, LVDCI, HSLVDCI, 1.5V	LVCMOS15, LVDCI_15, HSLVDCI_15	0.1	1.4	0.75	–
LVCMOS, LVDCI, HSLVDCI, 1.8V	LVCMOS18, LVDCI_18, HSLVDCI_18	0.1	1.7	0.9	–
HSTL (high-speed transceiver logic), class I, 1.2V	HSTL_I_12	V_{REF} – 0.25	V_{REF} + 0.25	V_{REF}	0.6
HSTL, class I, 1.5V	HSTL_I	V_{REF} – 0.325	V_{REF} + 0.325	V_{REF}	0.75
HSTL, class I, 1.8V	HSTL_I_18	V_{REF} – 0.4	V_{REF} + 0.4	V_{REF}	0.9
HSUL (high-speed unterminated logic), 1.2V	HSUL_12	V_{REF} – 0.25	V_{REF} + 0.25	V_{REF}	0.6
SSTL12 (stub series terminated logic), 1.2V	SSTL12	V_{REF} – 0.25	V_{REF} + 0.25	V_{REF}	0.6
SSTL135 and SSTL135 class II, 1.35V	SSTL135, SSTL135_II	V_{REF} – 0.2875	V_{REF} + 0.2875	V_{REF}	0.675
SSTL15 and SSTL15 class II, 1.5V	SSTL15, SSTL15_II	V_{REF} – 0.325	V_{REF} + 0.325	V_{REF}	0.75
SSTL18, class I and II, 1.8V	SSTL18_I, SSTL18_II	V_{REF} – 0.4	V_{REF} + 0.4	V_{REF}	0.9
POD10, 1.0V	POD10	V_{REF} – 0.2	V_{REF} + 0.2	V_{REF}	0.7
POD12, 1.2V	POD12	V_{REF} – 0.24	V_{REF} + 0.24	V_{REF}	0.84
DIFF_HSTL, class I, 1.2V	DIFF_HSTL_I_12	0.6 – 0.25	0.6 + 0.25	0 (6)	–
DIFF_HSTL, class I, 1.5V	DIFF_HSTL_I	0.75 – 0.325	0.75 + 0.325	0 (6)	–
DIFF_HSTL, class I, 1.8V	DIFF_HSTL_I_18	0.9 – 0.4	0.9 + 0.4	0 (6)	–

PLL Switching Characteristics

Table 34: **PLL Specification(1)**

Symbol	Description	Speed Grade and V_{CCINT} Operating Voltages				Units
		0.90V	0.85V		0.72V	
		-3	-2	-1	-2	
PLL_F_{INMAX}	Maximum input clock frequency.	1066	933	800	933	MHz
PLL_F_{INMIN}	Minimum input clock frequency.	70	70	70	70	MHz
PLL_$F_{INJITTER}$	Maximum input clock period jitter.	< 20% of clock input period or 1 ns Max				
PLL_F_{INDUTY}	Input duty cycle range: 70–399 MHz.	35–65				%
	Input duty cycle range: 400–499 MHz.	40–60				%
	Input duty cycle range: >500 MHz.	45–55				%
PLL_F_{VCOMIN}	Minimum PLL VCO frequency.	750	750	750	750	MHz
PLL_F_{VCOMAX}	Maximum PLL VCO frequency.	1500	1500	1500	1500	MHz
PLL_$T_{STATPHAOFFSET}$	Static phase offset of the PLL outputs.(2)	0.12	0.12	0.12	0.12	ns
PLL_$T_{OUTJITTER}$	PLL output jitter.	Note 3				
PLL_$T_{OUTDUTY}$	PLL CLKOUT0, CLKOUT0B, CLKOUT1, CLKOUT1B duty-cycle precision.(4)	0.165	0.20	0.20	0.20	ns
PLL_$T_{LOCKMAX}$	PLL maximum lock time.	100				µs
PLL_F_{OUTMAX}	PLL maximum output frequency at CLKOUT0, CLKOUT0B, CLKOUT1, CLKOUT1B.	891	775	667	725	MHz
	PLL maximum output frequency at CLKOUTPHY.	2667	2667	2400	2400	MHz
PLL_F_{OUTMIN}	PLL minimum output frequency at CLKOUT0, CLKOUT0B, CLKOUT1, CLKOUT1B.(5)	5.86	5.86	5.86	5.86	MHz
	PLL minimum output frequency at CLKOUTPHY.	2 x VCO mode: 1500 1 x VCO mode: 750 0.5 x VCO mode: 375				MHz
PLL_$RST_{MINPULSE}$	Minimum reset pulse width.	5.00	5.00	5.00	5.00	ns
PLL_F_{PFDMAX}	Maximum frequency at the phase frequency detector.	667.5	667.5	667.5	667.5	MHz
PLL_F_{PFDMIN}	Minimum frequency at the phase frequency detector.	70	70	70	70	MHz
PLL_$F_{BANDWIDTH}$	PLL bandwidth at typical.	14	14	14	14	MHz
PLL_F_{DPRCLK_MAX}	Maximum DRP clock frequency	250	250	250	250	MHz

Notes:

1. The PLL does not filter typical spread-spectrum input clocks because they are usually far below the loop filter frequencies.
2. The static offset is measured between any PLL outputs with identical phase.
3. Values for this parameter are available in the Clocking Wizard.
4. Includes global clock buffer.
5. Calculated as $F_{VCO}/128$ assuming output duty cycle is 50%.

Table 37: **Global Clock Input to Output Delay With MMCM**

Symbol	Description	Device	Speed Grade and V_{CCINT} Operating Voltages				Units
			0.90V	0.85V		0.72V	
			-3	-2	-1	-2	
SSTL15 Global Clock Input to Output Delay using Output Flip-Flop, Fast Slew Rate, with MMCM.							
$T_{ICKOFMMCMCC}$	Global clock input and output flip-flop *with* MMCM.	XCVU3P	1.80	1.80	1.94	2.34	ns
		XCVU5P	1.80	1.80	1.94	2.34	ns
		XCVU7P	1.80	1.80	1.94	2.34	ns
		XCVU9P	1.80	1.80	1.94	2.34	ns
		XCVU11P	1.56	1.56	1.68	2.07	ns
		XCVU13P	1.56	1.56	1.68	2.07	ns

Notes:

1. This table lists representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible I/O and CLB flip-flops are clocked by the global clock net in a single SLR.
2. MMCM output jitter is already included in the timing calculation.

Package Parameter Guidelines

The parameters in this section provide the necessary values for calculating timing budgets for clock transmitter and receiver data-valid windows.

Table 40: **Package Skew**

Symbol	Description	Device	Package	Value	Units
PKGSKEW	Package Skew	XCVU3P	FFVC1517	197	ps
		XCVU5P	FLVA2104	175	ps
			FLVB2104	225	ps
			FLVC2104	216	ps
		XCVU7P	FLVA2104	175	ps
			FLVB2104	225	ps
			FLVC2104	216	ps
		XCVU9P	FLGA2104	217	ps
			FLGB2104	275	ps
			FLGC2104	299	ps
			FSGD2104	229	ps
			FLGA2577	149	ps
		XCVU11P	FLGF1924	180	ps
			FLGB2104	216	ps
			FLGC2104		ps
			FSGD2104		ps
			FLGA2577	154	ps
		XCVU13P	FHGA2104		ps
			FHGB2104	259	ps
			FHGC2104	182	ps
			FIGD2104		ps
			FLGA2577	140	ps

Notes:

1. These values represent the worst-case skew between any two SelectIO resources in the package: shortest delay to longest delay from die pad to ball.
2. Package delay information is available for these device/package combinations. This information can be used to deskew the package.

GTY Transceiver Specifications

The *UltraScale Architecture and Product Overview* (DS890) lists the Virtex UltraScale+ FPGAs that include the GTY transceivers.

GTY Transceiver DC Input and Output Levels

Table 41 summarizes the DC specifications of the GTY transceivers in Virtex UltraScale+ FPGAs. Consult the *UltraScale Architecture GTY Transceiver User Guide* (UG578) for further information.

Table 41: **GTY Transceiver DC Specifications**

Symbol	DC Parameter	Conditions	Min	Typ	Max	Units
DV_{PPIN}	Differential peak-to-peak input voltage (external AC coupled)	>10.3125 Gb/s	150	–	1250	mV
		6.6 Gb/s to 10.3125 Gb/s	150	–	1250	mV
		≤ 6.6 Gb/s	150	–	2000	mV
V_{IN}	Single-ended input voltage. Voltage measured at the pin referenced to GND.	DC coupled $V_{MGTAVTT}$ = 1.2V	–400	–	$V_{MGTAVTT}$	mV
V_{CMIN}	Common mode input voltage	DC coupled $V_{MGTAVTT}$ = 1.2V	–	2/3 $V_{MGTAVTT}$	–	mV
D_{VPPOUT}	Differential peak-to-peak output voltage(1)	Transmitter output swing is set to 1010	800	–	–	mV
$V_{CMOUTDC}$	Common mode output voltage: DC coupled (equation based)	When remote RX is terminated to GND	$V_{MGTAVTT}/2 - D_{VPPOUT}/4$			mV
		When remote RX termination is floating	$V_{MGTAVTT} - D_{VPPOUT}/2$			mV
		When remote RX is terminated to V_{RX_TERM}(2)	$V_{MGTAVTT} - \frac{D_{VPPOUT}}{4} - \left(\frac{V_{MGTAVTT} - V_{RX\_TERM}}{2}\right)$			mV
$V_{CMOUTAC}$	Common mode output voltage: AC coupled	Equation based	$V_{MGTAVTT} - D_{VPPOUT}/2$			mV
R_{IN}	Differential input resistance		–	100	–	Ω
R_{OUT}	Differential output resistance		–	100	–	Ω
T_{OSKEW}	Transmitter output pair (TXP and TXN) intra-pair skew		–	–	10	ps
C_{EXT}	Recommended external AC coupling capacitor(3)		–	100	–	nF

Notes:

1. The output swing and pre-emphasis levels are programmable using the GTY transceiver attributes discussed in the *UltraScale Architecture GTY Transceiver User Guide* (UG578) and can result in values lower than reported in this table.
2. V_{RX_TERM} is the remote RX termination voltage.
3. Other values can be used as appropriate to conform to specific protocols and standards.

Table 48: **GTY Transceiver PLL/Lock Time Adaptation**

Symbol	Description	Conditions	All Speed Grades			Units
			Min	Typ	Max	
T_{LOCK}	Initial PLL lock.		–	–	1	ms
T_{DLOCK}	Clock recovery phase acquisition and adaptation time for decision feedback equalizer (DFE).	After the PLL is locked to the reference clock, this is the time it takes to lock the clock data recovery (CDR) to the data present at the input.	–	50,000	37×10^6	UI
	Clock recovery phase acquisition and adaptation time for low-power mode (LPM) when the DFE is disabled.		–	50,000	2.3×10^6	UI

Table 49: **GTY Transceiver User Clock Switching Characteristics(1)**

Symbol	Description	Data Width Conditions (Bit)		Speed Grade and V_{CCINT} Operating Voltages				Units
				0.90V	0.85V		0.72V	
		Internal Logic	Interconnect Logic	-3	-2	-1	-2	
$F_{TXOUTPMA}$	TXOUTCLK maximum frequency sourced from OUTCLKPMA			511.719	511.719	402.833	402.833	MHz
$F_{RXOUTPMA}$	RXOUTCLK maximum frequency sourced from OUTCLKPMA			511.719	511.719	402.833	402.833	MHz
$F_{TXOUTPROGDIV}$	TXOUTCLK maximum frequency sourced from TXPROGDIVCLK			511.719	511.719	511.719	511.719	MHz
$F_{RXOUTPROGDIV}$	RXOUTCLK maximum frequency sourced from RXPROGDIVCLK			511.719	511.719	511.719	511.719	MHz
F_{TXIN}	TXUSRCLK(2) maximum frequency	16	16, 32	511.719	511.719	390.625	390.625	MHz
		32	32, 64	511.719	511.719	390.625	390.625	MHz
		64	64, 128	511.719	440.781	402.832	402.832	MHz
		20	20, 40	409.375	409.375	312.500	312.500	MHz
		40	40, 80	409.375	409.375	312.500	350.000	MHz
		80	80, 160	409.375	352.625	322.266	352.625	MHz
F_{RXIN}	RXUSRCLK(2) maximum frequency	16	16, 32	511.719	511.719	390.625	390.625	MHz
		32	32, 64	511.719	511.719	390.625	390.625	MHz
		64	64, 128	511.719	440.781	402.832	402.832	MHz
		20	20, 40	409.375	409.375	312.500	312.500	MHz
		40	40, 80	409.375	409.375	312.500	350.000	MHz
		80	80, 160	409.375	352.625	322.266	352.625	MHz

Table 49: **GTY Transceiver User Clock Switching Characteristics(1) *(Cont'd)***

Symbol	Description	Data Width Conditions (Bit)		Speed Grade and V_{CCINT} Operating Voltages				Units
				0.90V	0.85V		0.72V	
		Internal Logic	Interconnect Logic	-3	-2	-1	-2	
F_{TXIN2}	TXUSRCLK2(2) maximum frequency	16	16	511.719	511.719	390.625	390.625	MHz
		16	32	255.859	255.859	195.313	195.313	MHz
		32	32	511.719	511.719	390.625	390.625	MHz
		32	64	255.859	255.859	195.313	195.313	MHz
		64	64	511.719	440.781	402.832	402.832	MHz
		64	128	255.859	220.391	201.416	201.416	MHz
		20	20	409.375	409.375	312.500	312.500	MHz
		20	40	204.688	204.688	156.250	156.250	MHz
		40	40	409.375	409.375	312.500	350.000	MHz
		40	80	204.688	204.688	156.250	175.000	MHz
		80	80	409.375	352.625	322.266	352.625	MHz
		80	160	204.688	176.313	161.133	176.313	MHz
F_{RXIN2}	RXUSRCLK2(2) maximum frequency	16	16	511.719	511.719	390.625	390.625	MHz
		16	32	255.859	255.859	195.313	195.313	MHz
		32	32	511.719	511.719	390.625	390.625	MHz
		32	64	255.859	255.859	195.313	195.313	MHz
		64	64	511.719	440.781	402.832	402.832	MHz
		64	128	255.859	220.391	201.416	201.416	MHz
		20	20	409.375	409.375	312.500	312.500	MHz
		20	40	204.688	204.688	156.250	156.250	MHz
		40	40	409.375	409.375	312.500	350.000	MHz
		40	80	204.688	204.688	156.250	175.000	MHz
		80	80	409.375	352.625	322.266	352.625	MHz
		80	160	204.688	176.313	161.133	176.313	MHz

Notes:

1. Clocking must be implemented as described in the *UltraScale Architecture GTY Transceiver User Guide* (UG578).
2. When the gearbox is used, these maximums refer to the XCLK. For more information, see the *Valid Data Width Combinations for TX Asynchronous Gearbox* table in the *UltraScale Architecture GTY Transceiver User Guide* (UG578).

Table 51: **GTY Transceiver Receiver Switching Characteristics**

Symbol	Description	Condition	Min	Typ	Max	Units
F_{GTYRX}	Serial data rate		0.500	–	F_{GTYMAX}	Gb/s
R_{XSST}	Receiver spread-spectrum tracking(1)	Modulated at 33 kHz	–5000	–	0	ppm
R_{XRL}	Run length (CID)		–	–	256	UI
$R_{XPPMTOL}$	Data/REFCLK PPM offset tolerance	Bit rates ≤ 6.6 Gb/s	–1250	–	1250	ppm
		Bit rates > 6.6 Gb/s and ≤ 8.0 Gb/s	–700	–	700	ppm
		Bit rates > 8.0 Gb/s	–200	–	200	ppm
SJ Jitter Tolerance(2)						
$J_{T\_SJ32.75}$	Sinusoidal jitter (QPLL)(3)	32.75 Gb/s	0.25	–	–	UI
$J_{T\_SJ28.21}$	Sinusoidal jitter (QPLL)(3)	28.21 Gb/s	0.30	–	–	UI
$J_{T\_SJ16.375}$	Sinusoidal jitter (QPLL)(3)	16.375 Gb/s	0.30	–	–	UI
$J_{T\_SJ15.0}$	Sinusoidal jitter (QPLL)(3)	15.0 Gb/s	0.30	–	–	UI
$J_{T\_SJ14.1}$	Sinusoidal jitter (QPLL)(3)	14.1 Gb/s	0.30	–	–	UI
$J_{T\_SJ13.1}$	Sinusoidal jitter (QPLL)(3)	13.1 Gb/s	0.30	–	–	UI
$J_{T\_SJ12.5}$	Sinusoidal jitter (QPLL)(3)	12.5 Gb/s	0.30	–	–	UI
$J_{T\_SJ11.3}$	Sinusoidal jitter (QPLL)(3)	11.3 Gb/s	0.30	–	–	UI
$J_{T\_SJ10.32\_QPLL}$	Sinusoidal jitter (QPLL)(3)	10.32 Gb/s	0.30	–	–	UI
$J_{T\_SJ10.32\_CPLL}$	Sinusoidal jitter (CPLL)(3)	10.32 Gb/s	0.30	–	–	UI
$J_{T\_SJ9.953\_QPLL}$	Sinusoidal jitter (QPLL)(3)	9.953 Gb/s	0.30	–	–	UI
$J_{T\_SJ9.953\_CPLL}$	Sinusoidal jitter (CPLL)(3)	9.953 Gb/s	0.30	–	–	UI
$J_{T\_SJ8.0}$	Sinusoidal jitter (CPLL)(3)	8.0 Gb/s	0.42	–	–	UI
$J_{T\_SJ6.6}$	Sinusoidal jitter (CPLL)(3)	6.6 Gb/s	0.44	–	–	UI
$J_{T\_SJ5.0}$	Sinusoidal jitter (CPLL)(3)	5.0 Gb/s	0.44	–	–	UI
$J_{T\_SJ4.25}$	Sinusoidal jitter (CPLL)(3)	4.25 Gb/s	0.44	–	–	UI
$J_{T\_SJ3.2}$	Sinusoidal jitter (CPLL)(3)	3.2 Gb/s(4)	0.45	–	–	UI
$J_{T\_SJ2.5}$	Sinusoidal jitter (CPLL)(3)	2.5 Gb/s(5)	0.30	–	–	UI
$J_{T\_SJ1.25}$	Sinusoidal jitter (CPLL)(3)	1.25 Gb/s(6)	0.30	–	–	UI
J_{T_SJ500}	Sinusoidal jitter (CPLL)(3)	500 Mb/s(7)	0.30	–	–	UI
SJ Jitter Tolerance with Stressed Eye(2)						
$J_{T\_TJSE3.2}$	Total jitter with stressed eye(8)	3.2 Gb/s	0.70	–	–	UI
$J_{T\_TJSE6.6}$		6.6 Gb/s	0.70	–	–	UI
$J_{T\_SJSE3.2}$	Sinusoidal jitter with stressed eye(8)	3.2 Gb/s	0.10	–	–	UI
$J_{T\_SJSE6.6}$		6.6 Gb/s	0.10	–	–	UI

Notes:

1. Using RXOUT_DIV = 1, 2, and 4.
2. All jitter values are based on a bit error ratio of 10^{-12}.
3. The frequency of the injected sinusoidal jitter is 80 MHz.
4. CPLL frequency at 3.2 GHz and RXOUT_DIV = 2.
5. CPLL frequency at 2.5 GHz and RXOUT_DIV = 2.
6. CPLL frequency at 2.5 GHz and RXOUT_DIV = 4.
7. CPLL frequency at 2.0 GHz and RXOUT_DIV = 8.
8. Composite jitter with RX equalizer enabled. DFE disabled.

Table 54: **Maximum Performance for Interlaken 6 x 25.78125 Gb/s and 6 x 28.21 Gb/s Protocol and Lane Logic Mode Designs**

Symbol	Description	Speed Grade and V_{CCINT} Operating Voltages										Units
		0.90V		0.85V				0.72V				
		-3(1)		-2(1)		-1		-2		-1		
$F_{RX\_SERDES\_CLK}$	Receive serializer/ deserializer clock	440.79		440.79		N/A		402.84		N/A		MHz
$F_{TX\_SERDES\_CLK}$	Transmit serializer/ deserializer clock	440.79		440.79		N/A		402.84		N/A		MHz
F_{DRP_CLK}	Dynamic reconfiguration port clock	250.00		250.00		N/A		250.00		N/A		MHz
		Min(2)	Max	Min(2)	Max	Min	Max	Min(2)	Max	Min	Max	
F_{CORE_CLK}	Interlaken core clock	412.50(3)	479.20	412.50(3)	479.20	N/A		412.50	429.69	N/A		MHz
F_{LBUS_CLK}	Interlaken local bus clock	300.00(4)	349.52	300.00(4)	349.52	N/A		300.00	349.52	N/A		MHz

Notes:

1. 6 x 28.21 mode is only supported in the -2 (V_{CCINT}=0.85V) and -3 (V_{CCINT}=0.90V) speed grades.
2. These are the minimum clock frequencies at the maximum lane performance.
3. The minimum value for CORE_CLK is 451.36 MHz for the 6 x 28.21 Gb/s protocol.
4. The minimum value for LBUS_CLK is 330.00 MHz for the 6 x 28.21 Gb/s protocol.

Table 55: **Maximum Performance for Interlaken 12 x 25.78125 Gb/s Lane Logic Only Mode Designs**

Symbol	Description	Speed Grade and V_{CCINT} Operating Voltages					Units
		0.90V	0.85V		0.72V		
		-3	-2	-1	-2	-1	
$F_{RX\_SERDES\_CLK}$	Receive serializer/ deserializer clock	402.84	402.84	N/A	N/A	N/A	MHz
$F_{TX\_SERDES\_CLK}$	Transmit serializer/ deserializer clock	402.84	402.84	N/A	N/A	N/A	MHz
F_{DRP_CLK}	Dynamic reconfiguration port clock	250.00	250.00	N/A	N/A	N/A	MHz
F_{CORE_CLK}	Interlaken core clock	412.50	412.50	N/A	N/A	N/A	MHz
F_{LBUS_CLK}	Interlaken local bus clock	349.52	349.52	N/A	N/A	N/A	MHz

Table 58: **System Monitor Specifications *(Cont'd)***

Parameter	Symbol	Comments/Conditions	Min	Typ	Max	Units
Supply sensor error(4)		Supply voltages 0.72V to 1.2V, T_j = –40°C to 100°C (with external REF)	–	–	±0.5	%
		Supply voltages 0.72V to 1.2V, T_j = –55°C to 125°C (with external REF)	–	–	±1.0	%
		All other supply voltages, T_j = –40°C to 100°C (with external REF)	–	–	±1.0	%
		All other supply voltages, T_j = –55°C to 125°C (with external REF)	–	–	±2.0	%
		Supply voltages 0.72V to 1.2V, T_j = –40°C to 100°C (with internal REF)	–	–	±1.0	%
		Supply voltages 0.72V to 1.2V, T_j = –55°C to 125°C (with internal REF)	–	–	±2.0	%
		All other supply voltages, T_j = –40°C to 100°C (with internal REF)	–	–	±1.5	%
		All other supply voltages, T_j = –55°C to 125°C (with internal REF)	–	–	±2.5	%
Conversion Rate(5)						
Conversion time—continuous	t_{CONV}	Number of ADCCLK cycles	26	–	32	Cycles
Conversion time—event	t_{CONV}	Number of ADCCLK cycles	–	–	21	Cycles
DRP clock frequency	DCLK	DRP clock frequency	8	–	250	MHz
ADC clock frequency	ADCCLK	Derived from DCLK	1	–	5.2	MHz
DCLK duty cycle			40	–	60	%
SYSMON Reference(6)						
External reference	V_{REFP}	Externally supplied reference voltage	1.20	1.25	1.30	V
On-chip reference		Ground V_{REFP} pin to AGND, T_j = –40°C to 100°C	1.2375	1.25	1.2625	V
		Ground V_{REFP} pin to AGND, T_j = –55°C to 125°C	1.225	1.25	1.275	V

Notes:

1. ADC offset errors are removed by enabling the ADC automatic offset calibration feature. The values are specified for when this feature is enabled.
2. See the *Analog Input* section in the *UltraScale Architecture System Monitor User Guide* (UG580).
3. When reading temperature values directly from the PMBus interface, the SYSMON has a +4°C offset due to the transfer function used by the PMBus application. For example, the external REF temperature sensor error's range of ±3°C becomes +1°C to +7°C when the temperature is read through the PMBus interface.
4. Supply sensor offset and gain errors are removed by enabling the automatic offset and gain calibration feature. The values are specified for when this feature is enabled.
5. See the *Adjusting the Acquisition Settling Time* section in the *UltraScale Architecture System Monitor User Guide* (UG580).
6. Any variation in the reference voltage from the nominal V_{REFP} = 1.25V and V_{REFN} = 0V will result in a deviation from the ideal transfer function. This also impacts the accuracy of the internal sensor measurements (i.e., temperature and power supply). However, for external ratiometric type applications allowing reference to vary by ±4% is permitted.

Revision History

The following table shows the revision history for this document.

Date	Version	Description of Revisions
04/19/2017	1.1	Updated the Summary description. In Table 1, updated Note 6, added data, and added Note 7, Note 8, and Note 9. Updated and added data to Table 2 though Table 6. Removed the -1LI speed grade. Updated Table 16, Table 17, and Table 18 to production release in Vivado Design Suite 2017.1 for the XCVU3P: -2E, -2I, -1E, -1I. Updated Table 15. Added Note 1 to Table 17. Updated Table 19, Table 20, Table 24, Table 25, Table 26, Table 28, Table 29, and Table 30. Added Table 21. Added MMCM_F_{DPRCLK_MAX} to Table 33 and PLL_F_{DPRCLK_MAX} to Table 34. Updated to Vivado Design Suite 2017.1 Table 35, Table 36, Table 37, and Table 38. Added data to Table 39 and Table 40. Updated the GTY Transceiver Specifications section. Revised the Integrated Interface Block for Interlaken section. Updated the System Monitor Specifications section adding notes to the tables. Updated the Configuration Switching Characteristics section. Removed the *eFUSE Programming Conditions* table and added the specifications to Table 2 and Table 3. Updated the Automotive Applications Disclaimer.
04/20/2016	1.0	Initial Xilinx release.

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